transition metal atoms in the plane and six above and below it in planar kagomé nets (*i.e.* nets with only 3636 tessellations). In the present structure there are in the mirror planes rhombs formed by Nd atoms which are surrounded by B and Fe atoms. The sigma-phase nets (which contain 3636, 6³, and 3²6² tessellations) above and below the mirror plane are severely puckered in such a way that Fe(6) (which is above and below a B-B connected line) is $1 \cdot 1$ Å closer to that plane than the pair of Fe(5) atoms (which lies above and below the Nd rhomb).

The structure of $Nd_2Fe_{14}B$ also resembles that of Mn_5SiC (Spinat, Fruchart, Kabbani & Herpin, 1970), which consists of two layers and one subsidiary layer of Laves-type structure (MgZn₂, C14), sandwiched between mirror planes which are less densely populated by Mn and C atoms. In this case the puckered sigma-phase nets in $Nd_2Fe_{14}B$ consisting of *hexagons* and triangles are replaced by less puckered nets of *pentagons* and triangles which occur in MgZn₂ perpendicular to [110] (Shoemaker & Shoemaker, 1967). In both cases the 'interstitial' atoms (B in $Nd_2Fe_{14}B$ and C in Mn_5SiC) are in trigonal prisms connecting pairs of double layers together.

Computations were performed with the aid of a grant from the Oregon State University Computer Center.

References

- BERGMAN, G. & SHOEMAKER, D. P. (1954). Acta Cryst. 7, 857-865.
- HERBST, J. F., CROAT, J. J., PINKERTON, F. E. & YELON, W. B. (1984). *Phys. Rev. B*, **29**, 4176–4178.
- HOPE, H. (undated). Private communication.
- International Tables for X-ray Crystallography (1974). Vol. IV, pp. 149, 99. Birmingham: Kynoch Press.
- JOHNSON, C. K. (1976). ORTEPII. Report ORNL-5138. Oak Ridge National Laboratory, Tennessee.
- MAIN, P., HULL, S. E., LESSINGER, L., GERMAIN, G., DECLERCQ, J.-P. & WOOLFSON, M. M. (1978). MULTAN78. A System of Computer Programs for the Automatic Solution of Crystal Structures from X-ray Diffraction Data. Univs. of York, England, and Louvain, Belgium.
- SAGAWA, M., FUJIMURA, S., TOGAWA, M., YAMAMOTO, H. & MATSUURA, Y. (1983). Conf. on Magnetism and Magnetic Materials, Nov. 1983, Pittsburgh, USA, Paper EBO1.
- SHOEMAKER, C. B. & SHOEMAKER, D. P. (1967). Acta Cryst. 23, 231-238.
- SPINAT, P., FRUCHART, R., KABBANI, M. & HERPIN, P. (1970). Bull. Soc. Fr. Minéral. Cristallogr. 93, 171–184.
- ZALKIN, A. (undated). X-ray program system. Lawrence Berkeley Laboratory, Berkeley, California.

Acta Cryst. (1984). C40, 1668-1670

A New Ordered Structure of the C15-Type Laves Phase, Mg_{28,4}Cu_{57,9}Si_{13,7}

BY T. MATSUNAGA, E. KODERA* AND Y. KOMURA[†]

Faculty of Science, Hiroshima University, Higashi-senda-machi, Naka-ku, Hiroshima 730, Japan

(Received 10 May 1984; accepted 7 June 1984)

Abstract. $M_r/100 = 47.54$, cubic, space group $P4_132$ (or $P4_332$), a = 6.9598 (4) Å, V = 337.12 Å³, $D_m = 5.66$ (2), $D_x = 5.62$ Mg m⁻³, 24 atoms per unit cell, λ (Mo $K\alpha$) = 0.7107 Å, μ (Mo $K\alpha$) = 22.8 mm⁻¹, F(000) = 530.7, R(F) = 0.046 for 82 independent reflections, room temperature. A new ordered structure of the Laves phase was found at the off-stoichiometric composition Mg₂Cu₃Si. The structure is characterized by ordered fourfold screw arrangements of Cu and Si atoms located on four tetrahedra in the unit cell leaving Mg atoms on 8(c) sites. The order parameter $S = \alpha_1 - \alpha_2$ is estimated from the refinement of the structure to be 0.74 in this specimen; α_1 and α_2 are the occupancy factors of Cu on sites 12(d) and 4(a) of $P4_132$, respectively.

⁺ To whom correspondence should be addressed.

0108-2701/84/101668-03**\$**01.50

Introduction. Laves phases are classified into the three fundamental structures C14, C15 and C36 which are typified by MgZn₂, MgCu₂ and MgNi₂, respectively. These structures were analyzed by Friauf (1927a,b)and Laves & Witte (1935). The pseudo-binary system MgCu₂-MgSi₂ has been studied thoroughly by Witte (1939). In this system the terminal solid solution of the cubic C15 type (MgCu, structure) extends from MgCu, to 20% MgSi₂; the hexagonal C14 type (MgZn, structure) then follows in the range 25-35% MgSi₂. The structure of the latter phase whose ideal composition is Mg₂Cu₃Si has shown an ordered arrangement of Cu and Si in the 6(h) and 2(a) sites, respectively, in $P6_3/mmc$. Moreover, a disordered C36-type structure was found as a high-temperature phase of the Mg₂-Cu₃Si compounds. Witte (1939) also found a compound $(Mg_6Cu_{16}Si_7)$ having the $D8_a$ -type structure away from the pseudo-binary section of MgX_2 . Ellner & Predel (1979) have carried out X-ray and neutron

© 1984 International Union of Crystallography

^{*} Present address: Faculty of Education, Kobe University, 3-11 Tsurukabuto, Nada-ku, Kobe 657, Japan.

Table 1. Parameters obtained for ordered $Mg_{28.4}Cu_{57.9}Si_{13.7}$

	Site	x	у	z	$B(\dot{A}^2)$	a
Mg _{0.85} Cu _{0.15}	8(c)	0.00320 (64)	x	x	0.98 (10)	
$\alpha_1 Cu_1 (1-\alpha_1)Si$	12(d)	1	0.13092 (22)	$x + \frac{1}{4}$	0.63 (6)	0.979 (10)
$\alpha_2 Cu.(1-\alpha_2)Si$	4(a)	3	ž	1	0.54 (18)	0.237 (30)

diffraction examinations on polycrystalline Laves phases of C15 type in the systems MgCu₂-MgZn₂, MgCu₂-MgNi₂ and MgNi₂-MgZn₂. They found no indication of structural change or ordering within the existence range of the solid solutions.

In the present study, a new phase with an ordered structure of C15 type was found in the ternary system Mg-Cu-Si: $Mg_{28.4}Cu_{57.9}Si_{13.7}$, which is off-stoichiometric from a Laves-phase composition Mg_2Cu_3Si . The order parameters of the specimen were estimated by full-matrix least-squares refinements of the structure including occupancy factors for each site.

Experimental. From preliminary experiments the region where the C15-type ordered phase is stable was found at the off-stoichiometric composition MgX_2 . The composition of the specimen examined was Mg_{28,4}-Cu_{57 o}Si_{13.7}. The alloy ingot was prepared by melting pure Mg and Cu metals and Cu-Si mother alloy in an electrical-resistance furnace at 1270 K in the presence of flux (NaCl, KCl and CaCl, mixture) in order to prevent oxidation. The alloy ingot thus obtained was annealed for 10 d at 770 K ($T_c \simeq 870$ K from the preliminary experiment) in an argon-filled sealed silica tube. The composition of the alloy specimen was checked by atomic absorption measurement. A tiny single-crystal fragment of irregular shape (approximate sphere, radius 0.05 mm) was selected from the crushed ingot. Density measured pycnometrically. Laue and Weissenberg photographs showed Laue group m3m. systematic absences $l \neq 4n$ for 00*l*, indicating space group P4,32 or P4,32. Cell constants estimated from 25 interplanar spacings measured on the X-ray diffractometer with a least-squares fit. Reflection data with $|F| > 3\sigma(F)$ collected in the range $2\theta < 50.0^{\circ}$. Rigaku AFC-5 automated diffractometer, graphitemonochromated Mo Ka radiation. θ -2 θ -scan mode, scan speed $2^{\circ} \min^{-1}$, scan range $(1 \cdot 2 + 0 \cdot 5 \tan \theta)^{\circ}$. Backgrounds measured by stationary counting at the scan extremes for 2 s each. Reflections 800, 080, 008, 800, 080, 008 chosen as internal standards and measured every 100 reflections. Monitor-counting method adopted in order to decrease the influence of the primary-beam fluctuation. Lorentz-polarization corrections, but no absorption correction ($\mu r \simeq 1.1$). After averaging of symmetry-related reflections 82 independent reflections used for structure analysis. Atomic scattering factors for Mg, Cu and Si atoms and f' and f''values from International Tables for X-ray Crystal*lography* (1974). Structural parameters refined with the full-matrix least-squares program *RSFLS*-4 (*UNICS*, 1967) and unit weight for all |F|'s. With Lagrange's unknown-multiplier method (Okamura, Iwasaki & Ogawa, 1968), the *RSFLS* program was modified to be able to refine the order parameters α_1 and α_2 , which are occupancy factors for Cu atoms at sites 12(d) and 4(a), respectively. A scale factor, positional parameters and isotropic temperature factors for all atoms were then refined; R(F) = 0.046, S = 0.6655, $(\Delta/\sigma)_{max} = 0.12$, final $\Delta \rho$ excursions $\leq |9.5| \in Å^{-3}$.

Discussion. The final parameters are listed in Table 1.* Here it is assumed that site 8(c) is occupied by all the Mg atoms and by the excess (with respect to the composition Mg X_2) Cu atoms. The C15-type MgCu₂ crystal belongs to space group Fd3m, whereas the newly found ordered modification of C15 type crystallizes in space group $P4_132$ (or $P4_332$). No effort has been made to distinguish between 4_1 and 4_3 in the present study. The Cu-site 16(d) positions in Fd3m split into two independent sites 4(a) and 12(d) in P4,32 for Cu and Si atoms. The ordered structure is characterized by the ordered fourfold screw arrangements of Cu and Si atoms located on four tetrahedra in the unit cell, leaving Mg atoms on site 8(c). The 8(c) site is assumed to be occupied by all the Mg atoms and by the excess Cu atoms randomly. A stereoscopic view of the ordered structure is shown in Fig. 1 (ORTEP; Johnson, 1976).

The structure is closely related to that of the compound Al_2Mo_3C whose structure was analyzed by Jeitschko, Nowotny & Benesovsky (1962). The structure of this compound belongs to $P4_132$, and Al, Mo and C atoms are located respectively on sites 8(c), 12(d) and 4(a), just as in the present ordered phase. However, the structural parameters of sites 8(c) and 12(d) of Al_2Mo_3C differ considerably from the ordered Laves phase. In addition, if we allot Mg, Cu and Si

^{*} A list of structure factors has been deposited with the British Library Lending Division as Supplementary Publication No. SUP 39573 (2 pp.). Copies may be obtained through The Executive Secretary, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.



Fig. 1. Stereoscopic view of ordered $Mg_{28,4}Cu_{57,9}Si_{13,7}$. $\bigoplus Mg; \bigoplus Cu; \bigoplus Si.$

atoms to the positions of Al, Mo and C respectively, the alloy composition is Mg_2Cu_3Si . From the experimental results of Witte (1939), however, Mg_2Cu_3Si was found to be an ordered structure of C14 type ($MgZn_2$ structure). The C15-type ordered structure is stabilized only in the small region off the stoichiometric composition Mg_2Cu_3Si . The reason for this is left unresolved in the present study.

The long-range-order parameter defined after Warren (1969) is $S = \alpha_1 - \alpha_2$ even for such a non-stoichiometric composition; here α_1 and α_2 are occupancy factors for Cu atoms in sites 12(d) and 4(a), respectively. In the present specimen, the order parameter S was found to be 0.74 in contrast to S = 0.82 for the expected highest-order parameter for this composition when site 12(d) is occupied entirely by Cu atoms.

Interatomic distances were calculated from the parameters obtained; they are given in Table 2, where only distances less than 3.5 Å are included. Coordination polyhedra around Mg atoms and small atoms (Cu, Si) are CN16 Friauf polyhedra (Samson, 1958) and CN12 icosahedra, respectively. Site 12(d) in the C15-type ordered structure is occupied by Cu atoms preferentially as in the case of site 6(h) in the C14-type ordered structure. Coordination polyhedra around Cu atoms of both structures are formed by six Mg, four Cu and two Si atoms. However, the scheme of the ordered arrangement of Si atoms in the C15-type ordered structure is different from that found in the C14-type ordered structure, as can be seen in Fig. 2. C14- and C15-type structures can be represented as two- and three-layer structures respectively, from the viewpoint of the Laves layers defined by Komura (1962). In the C14-type ordered structure, Cu atoms are located only on kagomé nets and Si atoms are only on triangular nets. On the other hand, in the C15-type ordered structure, Cu and Si atoms exist on both kinds of nets.

We wish to thank Dr Yamamoto of Hiroshima University for assistance with the chemical analysis. The computations were carried out on a HITAC M-180 computer at the Information Processing Center of Hiroshima University. The present work has been supported partly by a Scientific Research Grant from the Ministry of Education, to which the authors' thanks are due.

Table 2. Interatomic distances (Å) in ordered $Mg_{28,4}Cu_{57,9}Si_{13,7}$

Cu means the atom in site 12(d) and Si that in 4(a).

Mg	Cu			
ŬMg × I	3.0908 (63)	$Mg \times 2$	2.9016 (47)	
$Mg \times 3$	2.9882 (63)	$Mg \times 2$	2.8795 (45)	
$Cu \times 3$	2.9016 (47)	$Mg \times 2$	2.8565 (47)	
Cu × 3	2.8795 (45)	Cu × 4	2.4903 (19)	
Cu × 3	2.8565 (47)	$Si \times 2$	2.4320 (11)	
$Si \times 3$	2.9057 (45)			
Si				
Mg × 6	2.9057 (45)			
Cu × 6	2-4320 (11)			



Fig. 2. Coordination polyhedra around Cu atoms in (a) C15-type and (b) C14-type ordered structures.

References

- ELLNER, M. & PREDEL, B. (1979). J. Solid State Chem. 30, 209-221.
- FRIAUF, J. B. (1927a). Phys. Rev. 29, 35-40.
- FRIAUF, J. B. (1927b). J. Am. Chem. Soc. 49, 3107-3114.
- International Tables for X-ray Crystallography (1974). Vol. IV. Birmingham: Kynoch Press.
- JEITSCHKO, W., NOWOTNY, H. & BENESOVSKY, F. (1962). Monatsh. Chem. 94, 247-251.
- JOHNSON, C. K. (1976). ORTEPII. Report ORNL-5138. Oak Ridge National Laboratory, Tennessee.
- KOMURA, Y. (1962). Acta Cryst. 15, 770-778.
- LAVES, F. & WITTE, H. (1935). Metallwirtsch. Metallwiss. Metalltech. 14, 645-649.
- OKAMURA, K., IWASAKI, H. & OGAWA, S. (1968). J. Phys. Soc. Jpn, 24, 569–579.
- SAMSON, S. (1958). Acta Cryst. 11, 851-857.
- UNICS (1967). Universal Crystallographic Computation Program System, edited by T. SAKURAI. Crystallographic Society of Japan.
- WARREN, B. E. (1969). X-ray Diffraction. Reading, Mass.: Addison-Wesley.
- WITTE, H. (1939). Metallwirtsch. Metallwiss. Metalltech. 18. 459-463.